



IPW

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q80440

Masatomo SHIBATA

Appln. No.: 10/799,889

Group Art Unit: 2814

Confirmation No.: 8332

Examiner: PHAM, LONG

Filed: March 15, 2004

For: III-V NITRIDE SEMICONDUCTOR SUBSTRATE AND ITS PRODUCTION LOT,
AND III-V NITRIDE SEMICONDUCTOR DEVICE AND ITS PRODUCTION
METHOD

RESPONSE TO ACTION OF AUGUST 4, 2005

MAIL STOP AMENDMENT

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

Please consider the following Applicant's Response to the outstanding rejection of
August 4, 2005.

Please
enter (12/26/05)